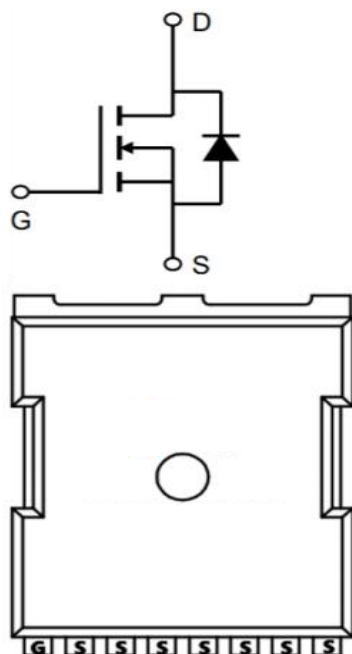


Description

The SX320N04TLG5 uses advanced technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.



General Features

$V_{DS} = 40V$ $I_D = 320A$

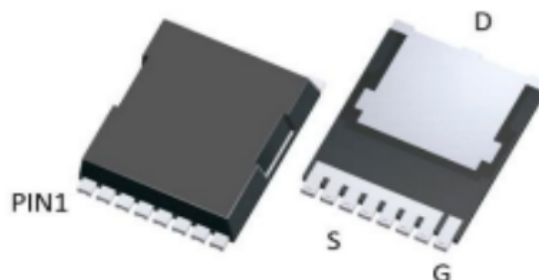
$R_{DS(ON)} < 1.0m\Omega$ @ $V_{GS}=10V$

Application

BMS

BLDC

UPS



Absolute Maximum Ratings ($T_c=25^\circ C$ unless otherwise noted)

Symbol	Parameter	Max.	Units
V_{DSS}	Drain-Source Voltage	40	V
V_{GSS}	Gate-Source Voltage	± 20	V
$I_{D@TC=25^\circ C}$	Continuous Drain Current, $V_{GS} @ 10V$	320	A
$I_{D@TC=100^\circ C}$	Continuous Drain Current, $V_{GS} @ 10V$	130	A
I_{DM}	Pulsed Drain Current	1200	A
EAS	Single Pulsed Avalanche Energy	610	mJ
IAS	Avalanche Current	70	A
$PD@TC=25^\circ C$	Power Dissipation	230	W
$R_{\theta JA}$	Thermal Resistance Junction-Ambient ¹	35	$^\circ C/W$
$R_{\theta JC}$	Thermal Resistance, Junction to Case	1.4	$^\circ C/W$
T_J	Operating Junction Temperature Range	-55 to 150	$^\circ C$
TSTG	Storage Temperature Range	-55 to 150	$^\circ C$

Electrical Characteristics (T_J=25 °C, unless otherwise noted)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
V(BR)DSS	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =250μA	40	48	-	V
IDSS	Zero Gate Voltage Drain Current	V _{DS} =40V, V _{GS} =0V,	-	-	1.0	μA
IGSS	Gate to Body Leakage Current	V _{DS} =0V, V _{GS} = ±20V	-	-	±100	nA
VGS(th)	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =250μA	1.0	1.5	2.5	V
RDS(on)	Static Drain-Source on-Resistance	V _{GS} =10V, I _D =30A	-	0.88	1.0	mΩ
		V _{GS} =4.5V, I _D =20A	-	1.1	1.5	mΩ
Ciss	Input Capacitance	V _{DS} =20V, V _{GS} =0V, f=1.0MHz	-	7400	-	pF
Coss	Output Capacitance		-	1930	-	pF
Crss	Reverse Transfer Capacitance		-	110	-	pF
Q _g	Total Gate Charge	V _{DS} =20V, I _D =85A, V _{GS} =10V	-	125	-	nC
Q _{gs}	Gate-Source Charge		-	18	-	nC
Q _{gd}	Gate-Drain("Miller") Charge		-	13	-	nC
td(on)	Turn-on Delay Time	V _{DD} =20V, I _D =85A, R _G =1.6Ω, V _{GS} =10V	-	14.1	-	ns
tr	Turn-on Rise Time		-	7.9	-	ns
td(off)	Turn-off Delay Time		-	56.5	-	ns
tf	Turn-off Fall Time		-	9.6	-	ns
IS	Maximum Continuous Drain to Source Diode Forward Current		-	-	200	A
ISM	Maximum Pulsed Drain to Source Diode Forward Current		-	-	800	A
VSD	Drain to Source Diode Forward Voltage	V _{GS} =0V, I _S =30A	-	-	1.2	V
trr	Body Diode Reverse Recovery Time	T _J =25°C, I _F =I _S , dI/dt=100A/μs	-	35	-	ns
Q _{rr}	Body Diode Reverse Recovery Charge		-	124	-	nC

Note :

- 1、The data tested by surface mounted on a 1 inch 2 FR-4 board with 2OZ copper.
- 2、The data tested by pulsed , pulse width ≤ 300us , duty cycle ≤ 2%
- 3、The EAS data shows Max. rating . The test condition is VDD =32V,VGS =10V,L=0.1mH,IAS =70A
- 4、The power dissipation is limited by 150°Cjunction temperature
- 5、The data is theoretically the same as I D and I DM , in real applications , should be limited by total power dissipation.

Typical Characteristics

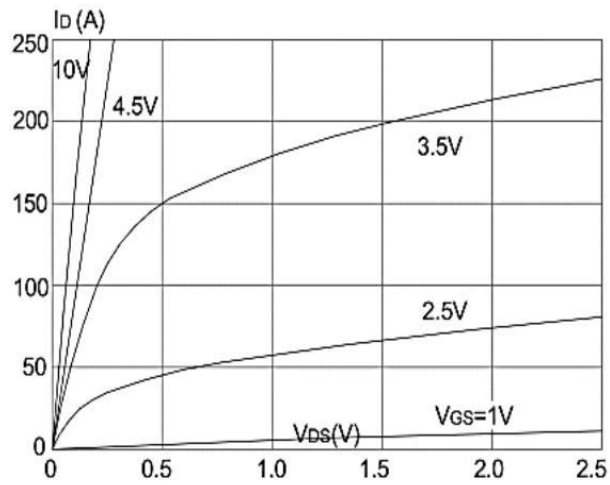


Figure1: Output Characteristics

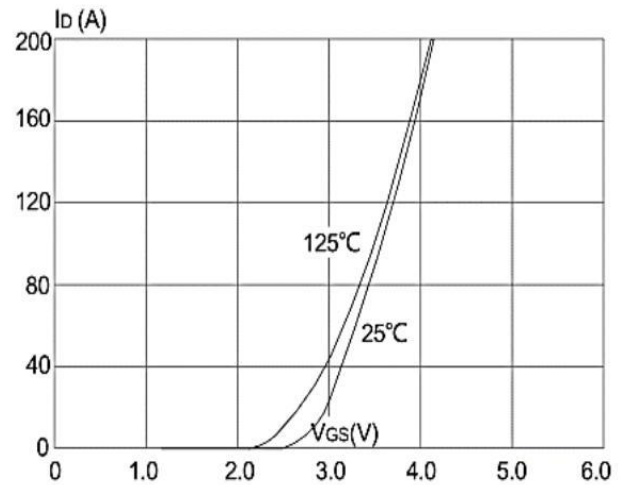


Figure 2: Typical Transfer Characteristics

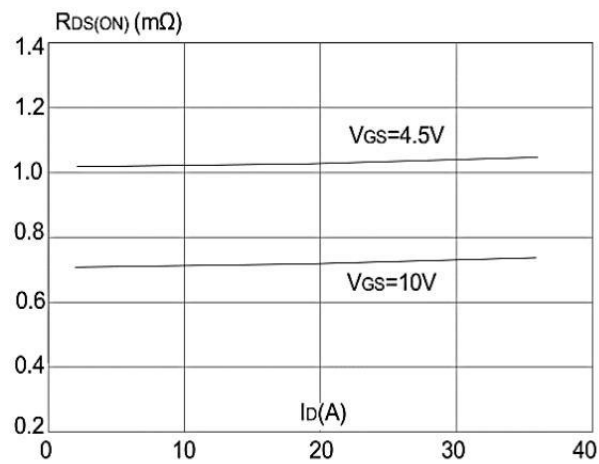


Figure 3: On-resistance vs. Drain Current

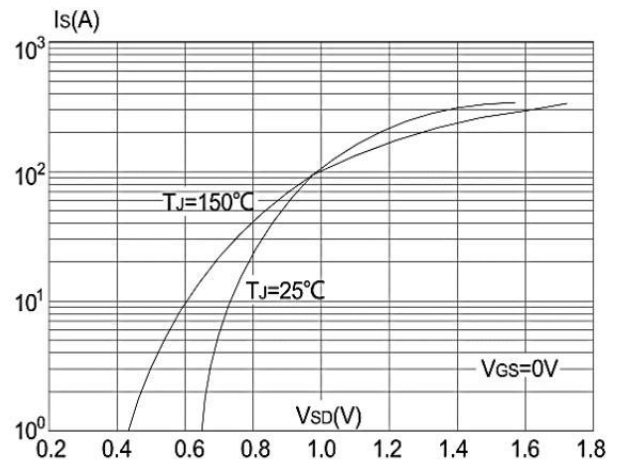


Figure 4: Body Diode Characteristics

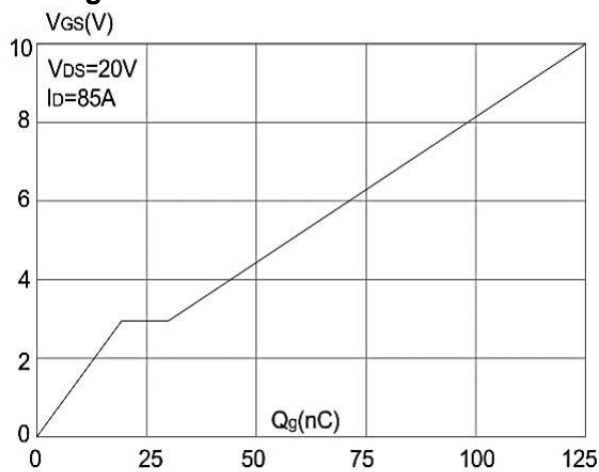


Figure 5: Gate Charge Characteristics

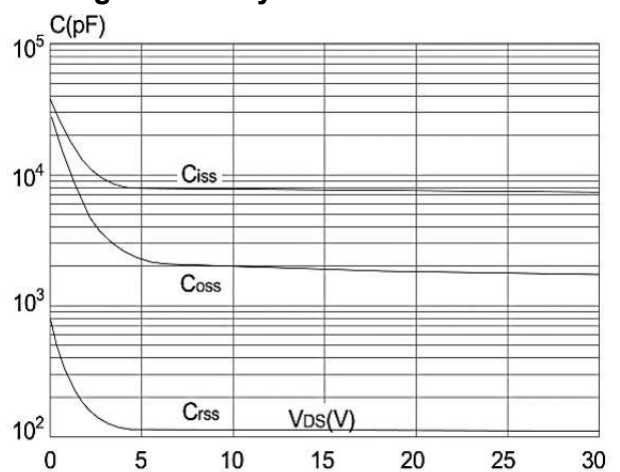


Figure 6: Capacitance Characteristics

Typical Characteristics

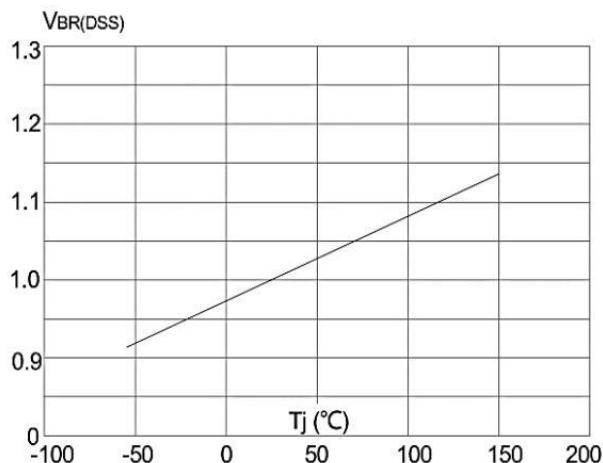


Figure 7: Normalized Breakdown Voltage vs. Junction Temperature

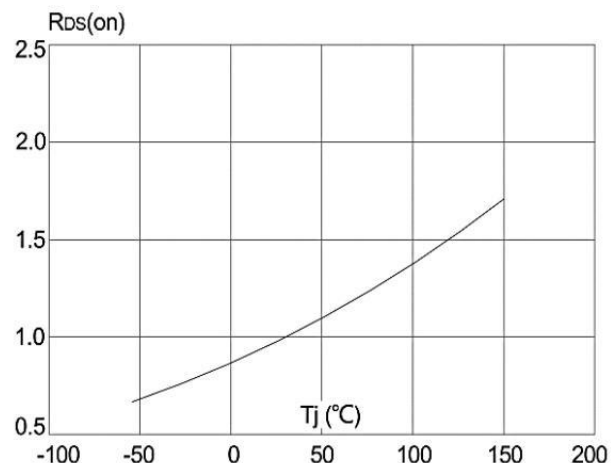


Figure 8: Normalized on Resistance vs. Junction Temperature

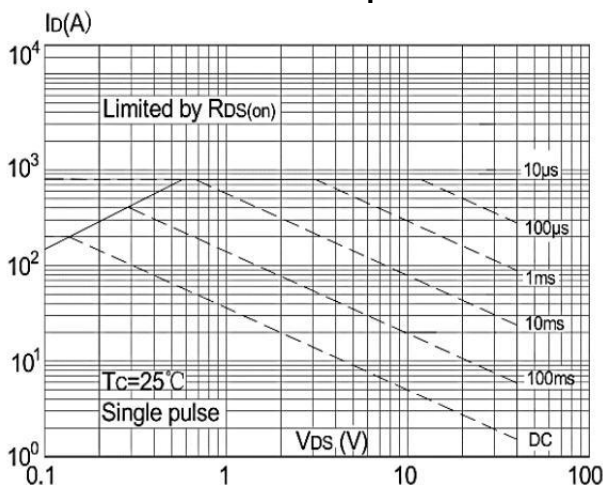


Figure 9: Maximum Safe Operating Area

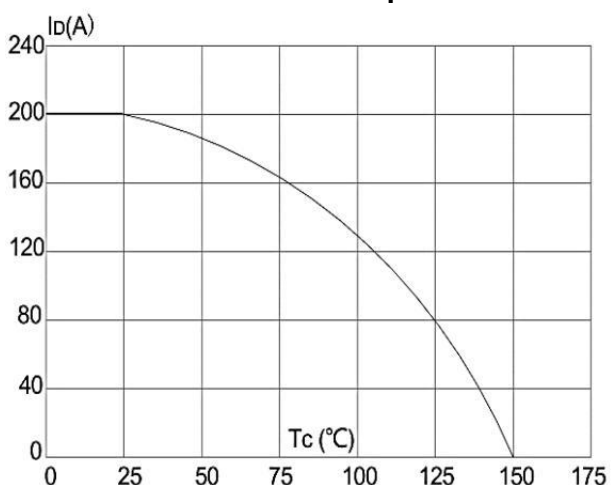


Figure 10: Maximum Continuous Drain Current vs. Case Temperature

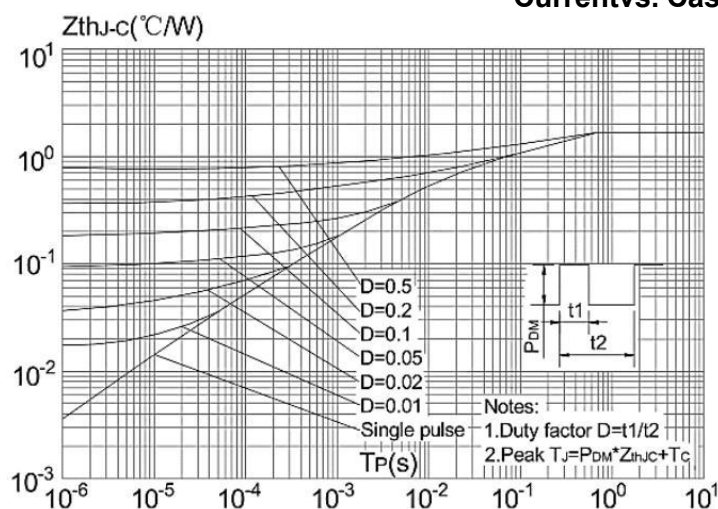
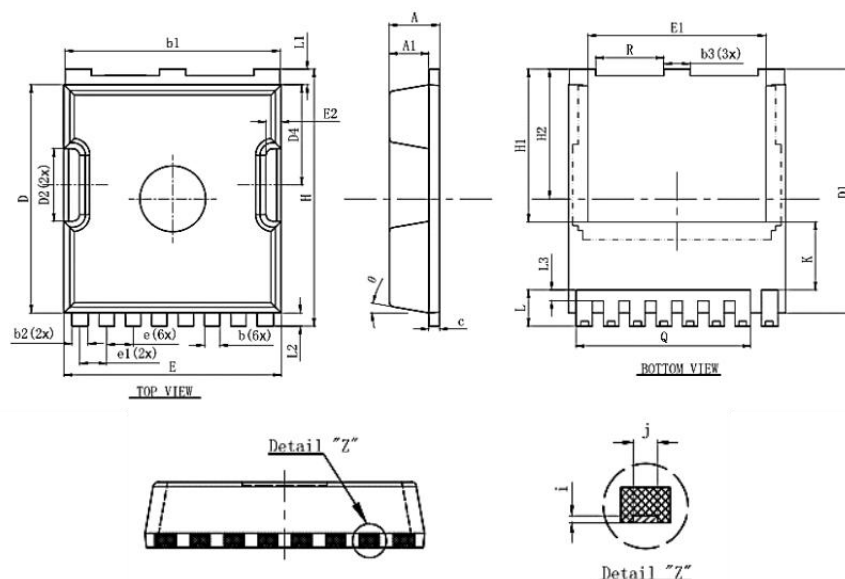


Figure.11: Maximum Effective Transient Thermal Impedance, Junction-to-Cas

Package Mechanical Data-TOLLA-8-XZ Single



Symbol	Dimensions In Millimeters		
	Min.	Nom	Max.
A	2.2	2.3	2.4
A1	1.7	1.8	1.9
b	0.6	0.7	0.8
b1	9.7	9.8	9.9
b2	0.65	0.75	0.85
b3	1.1	1.2	1.3
C	0.4	0.5	0.6
D	10.3	10.4	10.5
D1	11.0	11.1	11.2
D2	3.2	3.3	3.4
D4	4.47	4.57	4.67
E	9.8	9.9	10.0
E1	8.0	8.1	8.2
E2	0.5	0.6	0.7
e	1.200 (BSC)		
e1	1.225 (BSC)		
H	11.6	11.7	11.8
H1	6.95BSC		
H2	5.9BSC		
i	0.1REF		
j	0.350REF		
K	3.100REF		
L	1.55	1.65	1.75
L1	0.6	0.7	0.8
L2	0.5	0.6	0.7
L3	0.4	0.5	0.6
Q	7.95REF		
R	3.0	3.1	3.2
θ	10°REG		

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
TAPING	TOLLA-8L		2000